SCAS432 - JANUARY 1995

- Operates at 3-V to 3.6-V V_{CC}
- Load Clock and Unload Clock Can Be Asynchronous or Coincident
- Low-Power Advanced CMOS Technology
- Full, Empty, and Half-Full Flags
- Programmable Almost-Full/Almost-Empty Flag
- Fast Access Times of 18 ns With a 50-pF Load and All Data Outputs Switching Simultaneously
- Data Rates From 0 to 40 MHz
- 3-State Outputs
- Pin Compatible With SN74ACT7804
- Packaged in Shrink Small-Outline 300-mil Package (DL) Using 25-mil Center-to-Center Spacing

description

A FIFO memory is a storage device that allows data to be written into and read from its array at independent data rates. The SN74ALVC7804 is an 18-bit FIFO with high speed and fast access times. Data is processed at rates up to 40 MHz with access times of 18 ns in a bit-parallel format. The SN74ALVC7804 is designed for 3-V to 3.6-V V_{CC} operation.

Data is written into memory on a low-to-high transition of the load clock (LDCK) and is read out on a low-to-high transition of the unload clock (UNCK). The memory is full when the number of

RESET 56 N OE D17 $\prod 2$ 55 DQ17 D16 **∏**3 54**∏** Q16 53 Q15 D15 D14 5 52 1 GND D13 **∏**6 51 \ Q14 D12 50 ∏ V_{CC} D11 П8 49**∏** Q13 D10 48 \quad \qu 47 Q11 **1**0 V_{CC} D9 П 11 46**∏** Q10 D8 П 12 45**∏** Q9 GND 44 GND **1**3 D7 14 43 Q8 D6 **П** 15 42 \quad \qu D5 16 41 **∏** Q6 **1**7 40 DQ5 D4 **1**8 D3 39 V_{CC} D2 38**∏** Q4 П 19 П 20 D1 37 \ Q3 D0 **П** 21 36 \ Q2 HF 22 35 GND PEN 23 34 \ Q1 AF/AE П24 33 **∏** Q0 32 TUNCK LDCK 25 NC **1**26 31 NC NC **П** 27 30 NC FULL 28 29 **∏** EMPTY

DL PACKAGE

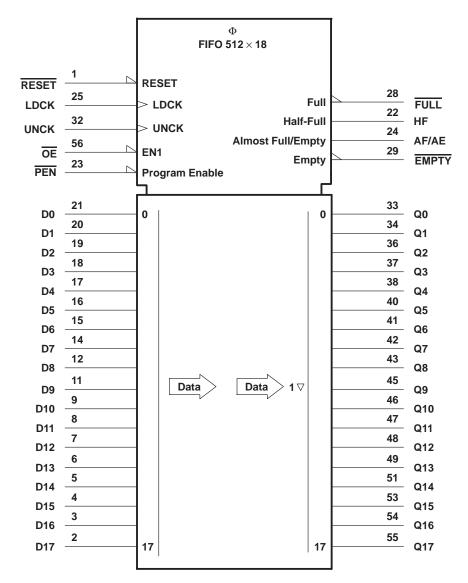
(TOP VIEW)

words clocked in exceeds the number of words clocked out by 512. When the memory is full, LDCK has no effect on the data residing in memory. When the memory is empty, UNCK has no effect.

Status of the FIFO memory is monitored by the full (FULL), empty (EMPTY), half-full (HF), and almost-full/almost-empty (AF/AE) flags. The FULL output is low when the memory is full and high when the memory is not full. The EMPTY output is low when the memory is empty and high when it is not empty. The HF output is high whenever the FIFO contains 256 or more words and is low when it contains 255 or less words. The AF/AE status flag is a programmable flag. The first one or two low-to-high transitions of LDCK after reset are used to program the almost-empty offset value (X) and the almost-full offset value (Y), if program enable (PEN) is low. The AF/AE flag is high when the FIFO contains X or less words or (512 minus Y) or more words. The AF/AE flag is low when the FIFO contains between (X plus 1) and (511 minus Y) words.

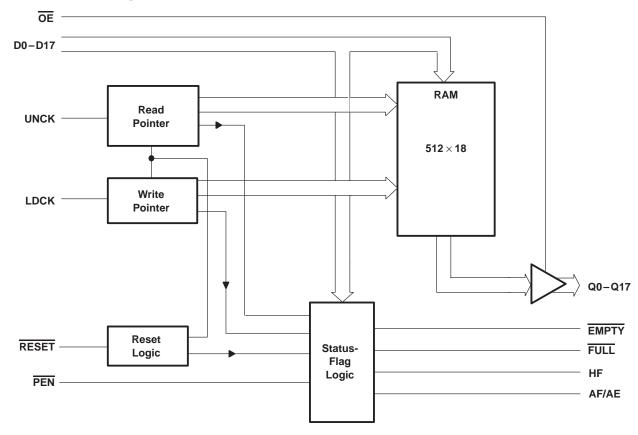
A low level on the reset (RESET) resets the internal stack pointers and sets FULL high, AF/AE high, HF low, and EMPTY low. The Q outputs are not reset to any specific logic level. The FIFO must be reset upon power up. The first word loaded into empty memory causes EMPTY to go high and the data to appear on the Q outputs. The data outputs are in the high-impedance state when the output-enable (OE) is high.

logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

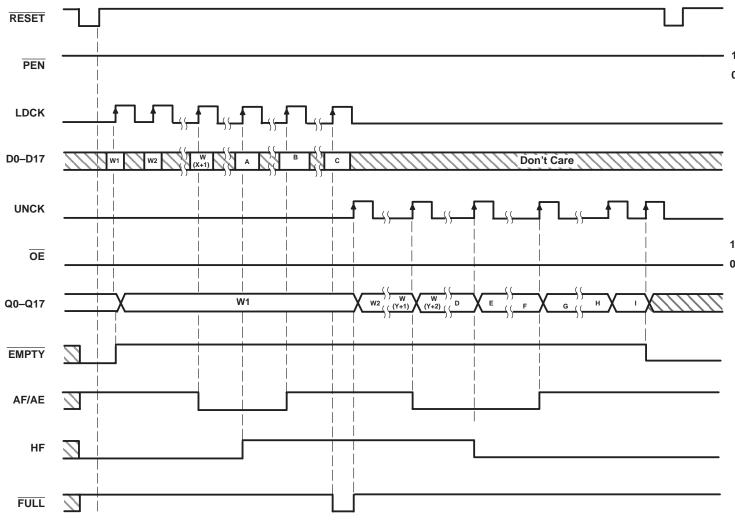
functional block diagram



Terminal Functions

TE	RMINAL	1/0	DESCRIPTION
NAME	NO.	I/O	DESCRIPTION
AF/AE	24	0	Almost full/almost empty flag. Depth offset values can be programmed for AF/AE, or the default value of 64 can be used for both the almost empty offset (X) and the almost full offset (Y). AF/AE is high when memory contains X or less words or (512 – Y) or more words. AF/AE is high after reset.
D0-D17	21-14, 12-11, 9-2	I	18-bit data input port
EMPTY	29	0	Empty flag. EMPTY is low when the FIFO is empty. A FIFO reset also causes EMPTY to go low.
FULL	28	0	Full flag. FULL is low when the FIFO is full. A FIFO reset causes FULL to go high.
HF	22	0	Half-full flag. HF is high when the FIFO memory contains 256 or more words. HF is low after reset.
LDCK	25	1	Load clock. Data is written to the FIFO on the rising edge of LDCK when FULL is high.
ŌE	56	I	Output enable. When OE is high, the data outputs are in the high-impedance state.
PEN	23	I	Program enable. After reset and before the first word is written to the FIFO, the binary value on D0-D7 is latched as an AF/AE offset value when PEN is low and WRTCLK is high.
Q0-Q17	33-34, 36-38, 40-43, 45-49, 51, 53-55	0	18-bit data output port
RESET	1	ı	Reset. A low level on RESET resets the FIFO and drives AF/AE and FULL high and HF and EMPTY low.
UNCK	32	I	Unload clock. Data is read from the FIFO on the rising edge of UNCK when EMPTY is high.





Define the AF/AE Flag
Using the Default Value of X and Y

Figure 1. Write, Read, and Flag Timing Reference

\mathbf{D}	ΔΤΔ	WORD	NUMBERS	FOR FLAG	TRANSITIONS
ш	MIM	WORD	MOMBERS	FUN FLAG	INANSIIIONS

DEVICE				TRA	NSITION W	ORD .			
DEVICE	Α	В	С	D	E	F	G	Н	1
SN74ALVC7804	W256	W(512-Y)	W512	W257	W258	W(512-X)	W(513-X)	W511	W512

offset values for AF/AE

The AF/AE flag has two programmable limits: the almost-empty offset value (X) and the almost-full offset value (Y). They can be programmed after the FIFO is reset and before the first word is written to memory. The AF/AE flag is high when the FIFO contains X or less words or (512 minus Y) or more words.

To program the offset values, \overline{PEN} can be brought low after reset. On the following low-to-high transition of LDCK, the binary value on D0–D7 is stored as the almost empty offset value (X) and the almost full offset value (Y). Holding \overline{PEN} low for another low-to-high transition of LDCK reprograms Y to the binary value on D0–D7 at the time of the second LDCK low-to-high transition. Writes to the FIFO memory are disabled while the offsets are programmed. A maximum value of 255 can be programmed for either X or Y (see Figure 2). To use the default values of X = Y = 64, \overline{PEN} must be held high.

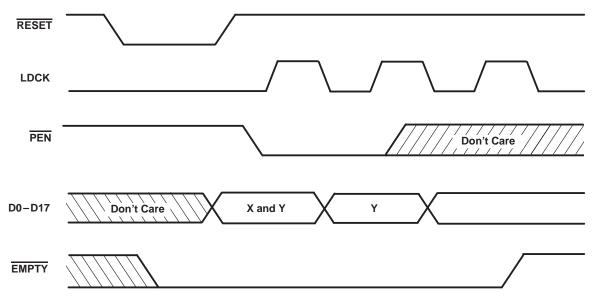


Figure 2. Programming X and Y Separately

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	0.5 V to 4.6 V
Output voltage range, V _O (see Notes 1 and 2)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I _{IK} (V _I < 0)	– 50 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±50 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Voltage applied to a disabled 3-state output	3.6 V
Operating free-air temperature range, T _A	0°C to 70°C
Storage temperature range	−65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

			V _{CC} = 3.3	7804-25 V ± 0.3 V		$V~\pm~0.3~V$	UNIT	
			MIN	MAX	MIN	MAX		
VIH	High-level input voltage		2		2		V	
V_{IL}	Low-level input voltage			8.0		0.8	V	
VI			0	VCC	0	Vcc	V	
Vo			0	VCC	0	Vcc	V	
ЮН	High-level output current, Q outputs, Flags	VCC = 3 V		-8		-8	mA	
lOL	Low-level output current, Q outputs, Flags	VCC = 3 V		16		16	mA	
f _{clock}	Clock frequency			40		25	MHz	
		D0-D17 high or low	8		12			
		LDCK high or low	8		12			
t _W	Pulse duration	UNCK high or low	8		12		ns	
		PEN low	8		12			
		RESET low	10		12			
		D0−D17 before LDCK↑	5		5			
t _{su}	Setup time	LDCK inactive before RESET high	6		6		ns	
		PEN before LDCK↑	8		8			
		D0−D17 after LDCK↑	0		0			
.	I lold time	PEN high after LDCK low	0		0			
th	Hold time	PEN low after LDCK↑	3		3		ns	
		LDCK inactive after RESET high	6		6			
TA	Operating free-air temperature		0	70	0	70	°C	

NOTES: 1. The input and output voltage ratings can be exceeded if the input and output clamp current ratings are observed.

^{2.} This value is limited to 4.6 V maximum.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PAR	AMETER	TEST CO	NDITIONS†	MIN TYP‡	MAX	UNIT
Vou	Flags O outputs	$V_{CC} = MIN \text{ to MAX},$	$I_{OH} = -100 \mu A$	V _{CC} −0.2		V
VOH	Flags, Q outputs	V _{CC} = 3 V,	$I_{OH} = -8 \text{ mA}$	2.4		V
	Flags, Q outputs	$V_{CC} = MIN \text{ to MAX},$	I _{OL} = 100 μA		0.2	
VOL	Flags	V _{CC} = 3 V,	$I_{OL} = 8 \text{ mA}$		0.4	V
	Q outputs	V _{CC} = 3 V,	$I_{OL} = 16 \text{ mA}$		0.55	
lį		$V_{CC} = 3.6 \text{ V},$	V _I =V _{CC} or GND		±5	μΑ
loz		$V_{CC} = 3.6 \text{ V},$	$V_O = V_{CC}$ or GND		±10	μΑ
ICC		V _{CC} = 3.6 V,	$V_I = V_{CC}$ or GND and $I_O = 0$		40	μΑ
ΔlCC§		V _{CC} = 3.6 V, Other inputs at V _{CC} or GND	One input at V _{CC} -0.6 V,		500	μΑ
Ci		$V_{CC} = 3.3 \text{ V},$	$V_I = V_{CC}$ or GND	3	·	pF
Co		V _{CC} = 3.3 V,	$V_O = V_{CC}$ or GND	6		pF

[†] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature, C_L = 50 pF (unless otherwise noted) (see Figure 5)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	'ALVC7 V _{CC} = 3.3	804-25 V ± 0.3 V	'ALVC7 V _{CC} = 3.3		UNIT
	(INPUT)	(001701)	MIN	MAX	MIN	MAX	
f _{max}	LDCK or UNCK		40		25		MHz
^t pd	LDCK↑	Any Q	9	22	9	24	ns
^t pd	UNCK↑	Ally Q	6	18	6	20	115
^t PLH	LDCK [↑]		6	17	6	19	
^t PHL	UNCK↑	EMPTY	6	17	6	19	ns
t _{PHL}	RESET low		4	18	4	20	
^t PHL	LDCK [↑]		6	17	6	19	
^t PLH	UNCK↑	FULL	6	17	6	19	ns
^t PLH	RESET low		4	20	4	22	
^t pd	LDCK [↑]		7	20	7	22	
^t pd	UNCK↑	AF/AE	7	20	7	22	ns
^t PLH	RESET low		2	12	2	14	
^t PLH	LDCK [↑]		5	20	5	22	
^t PHL	UNCK↑	HF	7	20	7	22	ns
^t PHL	RESET low		3	14	3	16	
^t en	ŌĒ	Any Q	2	10	2	11	no
t _{dis}	UE	Ally Q	2	11	2	12	ns

operating characteristics, $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$

	PARAMETER	TEST CON	TYP	UNIT		
C _{pd}	Power dissipation capacitance per FIFO channel	Outputs enabled	$C_L = 50 \text{ pF},$	f = 5 MHz	53	pF



[‡] All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$.

[§] This is the supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_{CC}.

APPLICATION INFORMATION

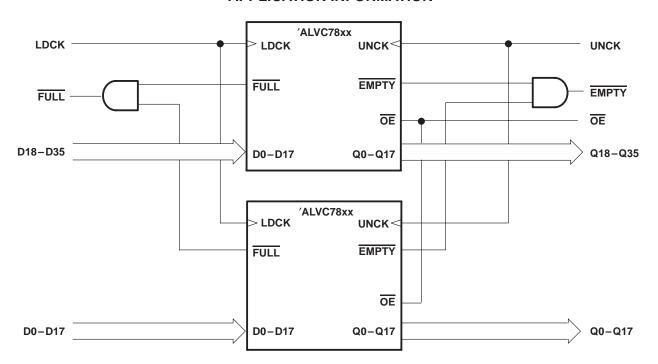


Figure 3. Word-Width Expansion: 512 imes 36 Bit



TYPICAL CHARACTERISTICS

SUPPLY CURRENT CLOCK FREQUENCY 140 f_{data} = 1/2 f_{clock} $T_A = 75^{\circ}C$ 120 CC(f) - Supply Current - mA $C_L = 0 pF$ $V_{CC} = 3.6 V$ 100 $V_{CC} = 3.3 V$ 80 60 $V_{CC} = 3 V$ 40 20 10 30 40 50 70 80 f_{clock} - Clock Frequency - MHz

Figure 4

calculating power dissipation

With $I_{CC(f)}$ taken from Figure 4, the dynamic power (P_d) , based on all data outputs changing states on each read, can be calculated by using:

$$P_{d} = V_{CC} \times [I_{CC(f)} + (N \times \Delta I_{CC} \times dc)] + \sum (C_{L} \times V_{CC}^{2} \times f_{o})$$

A more accurate total power (P_T) can be calculated if quiescent power (P_q) is also taken into consideration. Quiescent power (P_q) can be calculated using:

$$P_{q} = V_{CC} \times [I_{CCI} + (N \times \Delta I_{CC} \times dc)]$$

Total power will be:

$$P_T = P_d + P_q$$

The above equations provide worst-case power calculations.

Where:

N = number of inputs driven by TTL levels

 ΔI_{CC} = increase in power supply current for each input at a TTL high level

dc = duty cycle of inputs at a TTL high level of 3.4 V

C_L = output capacitance load

f_o = switching frequency of an output

 I_{CCI} = idle current, supply current when FIFO is idle \approx pF \times f_{clock} = 0.2 \times f_{clock}

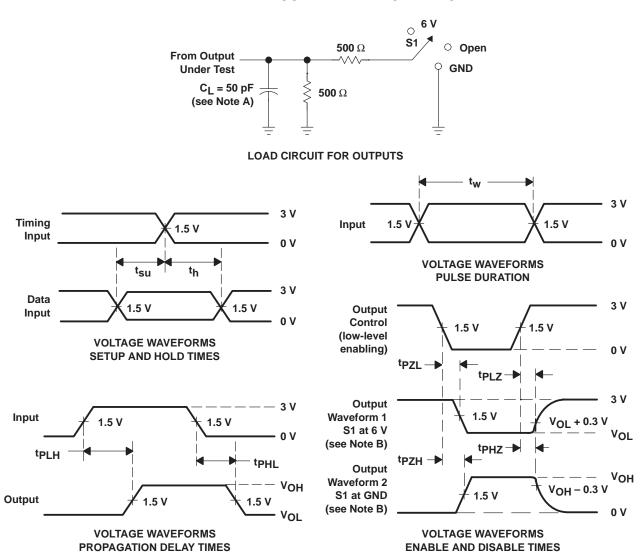
(current is due to free-running clocks)

pF = power factor (the slope of idle I_{CC} versus frequency)

I_{CC(f)} = active current, supply current when FIFO is transferring data



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \Omega$, $t_f \leq 2.5$ ns, $t_f \leq 2.5$ ns.

3-STATE OUTPUTS (ANY Q)

PARAM	METER	R1, R2	c _L †	S1
^t en	^t PZH	500 Ω	50 pF	GND
	tPZL	500 52	50 pr	6 V
4	^t PHZ	500 Ω	50 pF	GND
^t dis	t _{PLZ}	500 52	50 pr	6 V
t _{pd} t _{PLH} /t _{PHL}		500 Ω	50 pF	Open

[†] Includes probe and test-fixture capacitance

Figure 5. Standard CMOS Outputs (FULL, EMPTY, HF, AF/AE)



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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74ALVC7804-25DL	Active	Production	SSOP (DL) 56	20 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	ALVC7804-25
SN74ALVC7804-25DL.A	Active	Production	SSOP (DL) 56	20 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	See SN74ALVC7804-25DL	ALVC7804-25

⁽¹⁾ Status: For more details on status, see our product life cycle.

- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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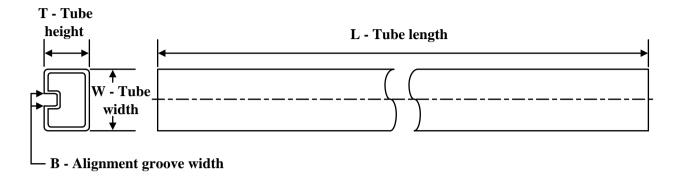
⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

PACKAGE MATERIALS INFORMATION

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TUBE

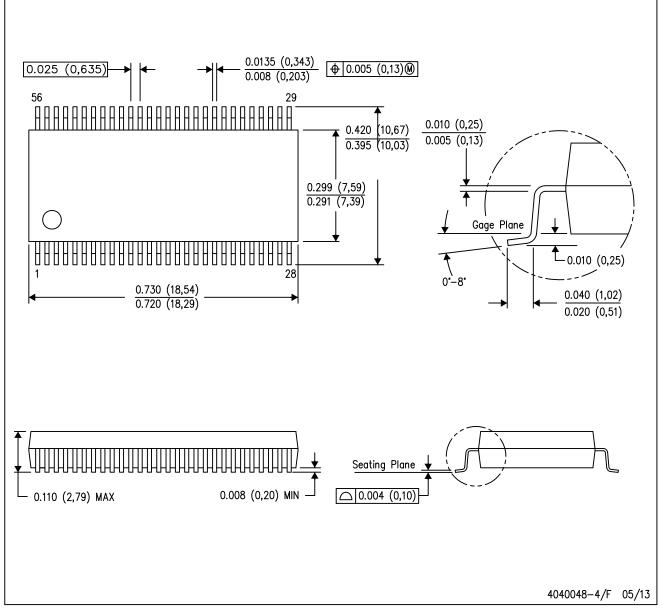


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74ALVC7804-25DL	DL	SSOP	56	20	473.7	14.24	5110	7.87
SN74ALVC7804-25DL.A	DL	SSOP	56	20	473.7	14.24	5110	7.87

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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